



DDR4

K4AAG165WB-MCRC



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Exceptional Speed, High Reliability, Low Energy Consumption

High-performing memory empowers faster, powerful solutions. Samsung DDR4 delivers top speed with better bandwidth and reliability using less energy.

- An Evolution in Performance
- Improved Reliability
- Less Energy, Greater Efficiency

Specifications

Density	16Gb	Org.	1G x 16
Speed	2400 Mbps	Voltage	1.2 V
Temp.	0 ~ 85 °C	Package	96FBGA
Product Status	Mass Production		

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Samsung Develops Industry's First 3rd-generation 10nm-Class DRAM

New 8Gb DDR4 based on most advanced 1z-nm process enables DRAM solutions with ultra-high performance and power efficiency.

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Industry-leading Semiconductor Solutions Showcased at CES 2019

At this year's CES, Samsung Electronics introduced its vision for the future of Connected Living and exhibited its most up-to-date solutions at the Las Vegas Convention Center.

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